Excellent Integrated System Limited

Stocking Distributor

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<u>Diodes Incorporated</u> <u>2DB1424R-13</u>

For any questions, you can email us directly: sales@integrated-circuit.com



Datasheet of 2DB1424R-13 - TRANS PNP 20V 3A SOT89-3

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2DB1424R

PNP SURFACE MOUNT TRANSISTOR

Features

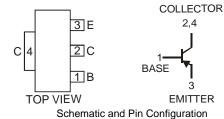
- Epitaxial Planar Die Construction
- Complementary NPN Type Available (2DD2150)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Mechanical Data

- Case: SOT89-3L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 3 Ordering Information: See Page 3
- Weight: 0.072 grams (approximate)







Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-20	V
Collector-Emitter Voltage	V_{CEO}	-20	V
Emitter-Base Voltage	V _{EBO}	-6	V
Peak Pulse Current	I _{CM}	-5	A
Continuous Collector Current	Ic	-3	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ T _A = 25°C	P _D	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ T _A = 25°C	$R_{\theta JA}$	125	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Conditions
OFF CHARACTERISTICS (Note 4)	1 -					
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-20	_	_	V	$I_C = -50\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-20	_	_	V	$I_{C} = -1 \text{mA}, I_{B} = 0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-6	_	_	V	$I_E = -50\mu A, I_C = 0$
Collector Cut-Off Current	I _{CBO}	_	_	-0.1	μΑ	$V_{CB} = -20V, I_{E} = 0$
Emitter Cut-Off Current	I _{EBO}	_	_	-0.1	μΑ	$V_{EB} = -5V, I_{C} = 0$
ON CHARACTERISTICS (Note 4)			_	_	_	
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	-0.18	-0.5	V	$I_C = -2A$, $I_B = -0.1A$
DC Current Gain	h _{FE}	180	_	390	_	$V_{CE} = -2V, I_{C} = -0.1A$
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C _{obo}	_	28	_	pF	$V_{CB} = -10V, I_{E} = 0,$ f = 1MHz
Current Gain-Bandwidth Product	f⊤	_	220	_	MHz	$V_{CE} = -2V, I_{E} = 0.1A,$ f = 100MHz

Notes:

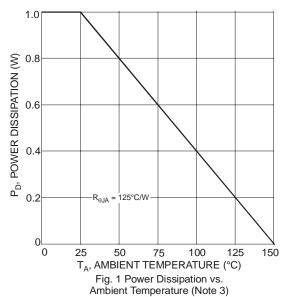
- No purposefully added lead.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- Device mounted on FR-4 PCB; pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can 3. be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- Measured under pulsed conditions. Pulse width = $300\mu s$. Duty cycle $\leq 2\%$.

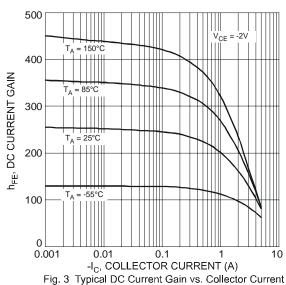


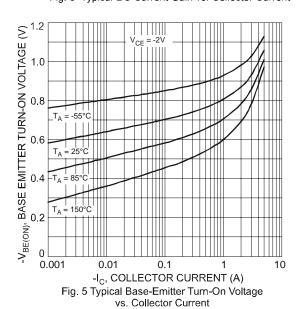
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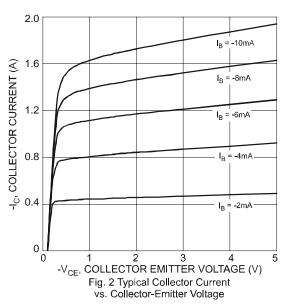
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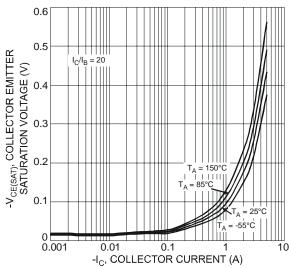


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

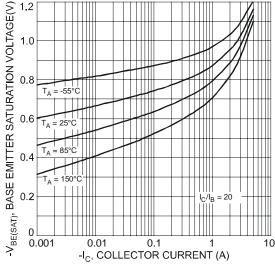


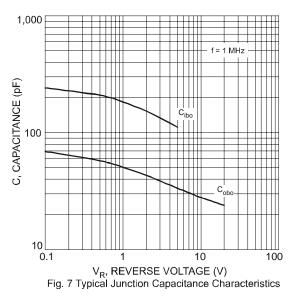
Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

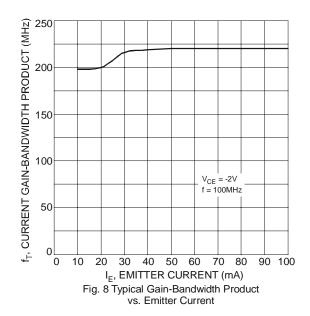


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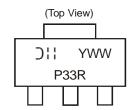


Ordering Information (Note 5)

Device	Packaging	Shipping
2DB1424R-13	SOT89-3L	2500/Tape & Reel

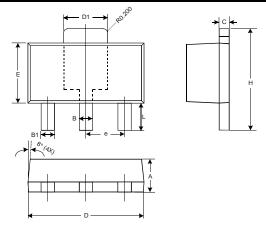
Notes: 5. For packaging details, please see below or go to our website at http://www.diodes.com/ap02007.pdf.

Marking Information



P33R = Product Type Marking Code YWW = Date Code Marking Y = Last digit of year ex: 7 = 2007 WW = Week code 01 - 52

Package Outline Dimensions



SOT89-3L					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.45	0.55	0.50		
B1	0.37	0.47	0.42		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.50	1.70	1.60		
Е	2.40	2.60	2.50		
е		_	1.50		
Н	3.95	4.25	4.10		
L	0.90	1.20	1.05		
All Dimensions in mm					

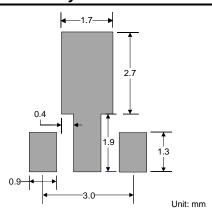


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Suggested Pad Layout



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